

KSA642

Low Frequency Power Amplifier

- Complement to KSD227
- Collector Power Dissipation : P_C = 400mW
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



1. Emitter 2. Base 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	-30	V
V _{CEO}	Collector-Emitter Voltage	-25	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current (DC)	-300	mA
I _{CP}	* Collector Current (Pulse)	-500	mA
P _C	Collector Power Dissipation	400	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

^{*} PW≤10ms, Duty cycle≤50%

Electrical Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = -100 \mu A, I_E = 0$	-30			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = -10mA. I _B =0	-25			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -10\mu A. I_C = 0$	- 5			V
I _{CBO}	Collector Cut-off Current	V _{CB} = -25V, I _E =0			-100	nA
I _{EBO}	Emitter Cut-off Current	V_{EB} = -3V, I_{C} =0			-100	nA
h _{FE}	* DC Current Gain	V_{CE} = -1V, I_{C} = -50mA	70		400	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C = -300mA, I _B = -30mA		-0.35	-0.6	V

^{*} Pulse Test: PW≤350μs, Duty cycle≤2%

h_{FE} Classification

Classification	0	Y	G
h _{FE}	70 ~ 140	120 ~ 240	200 ~ 400



Typical Characteristics

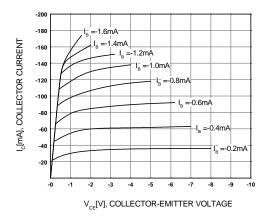


Figure 1. Static Characteristic

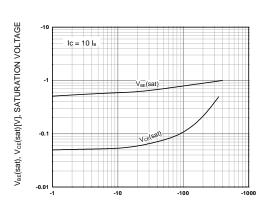


Figure 3. Base-Emitter Saturation Voltag Collector-Emitter Saturation Voltage

 $I_{\mathbb{C}}[mA]$, COLLECTOR CURRENT

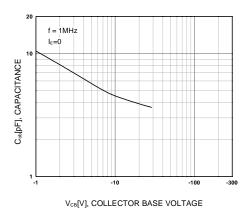


Figure 5. Collector Output Capacitance

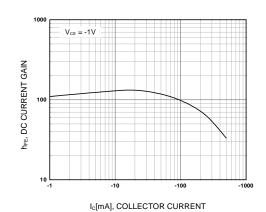


Figure 2. DC current Gain

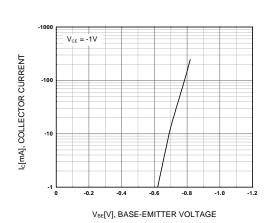
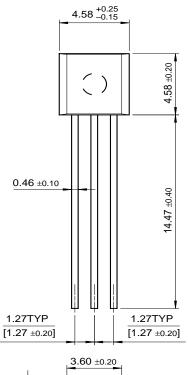


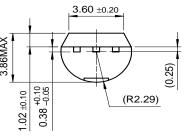
Figure 4. Base-Emitter On Voltage

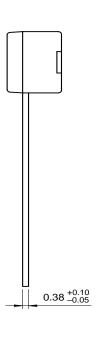
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Package Demensions

TO-92







Dimensions in Millimeters

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